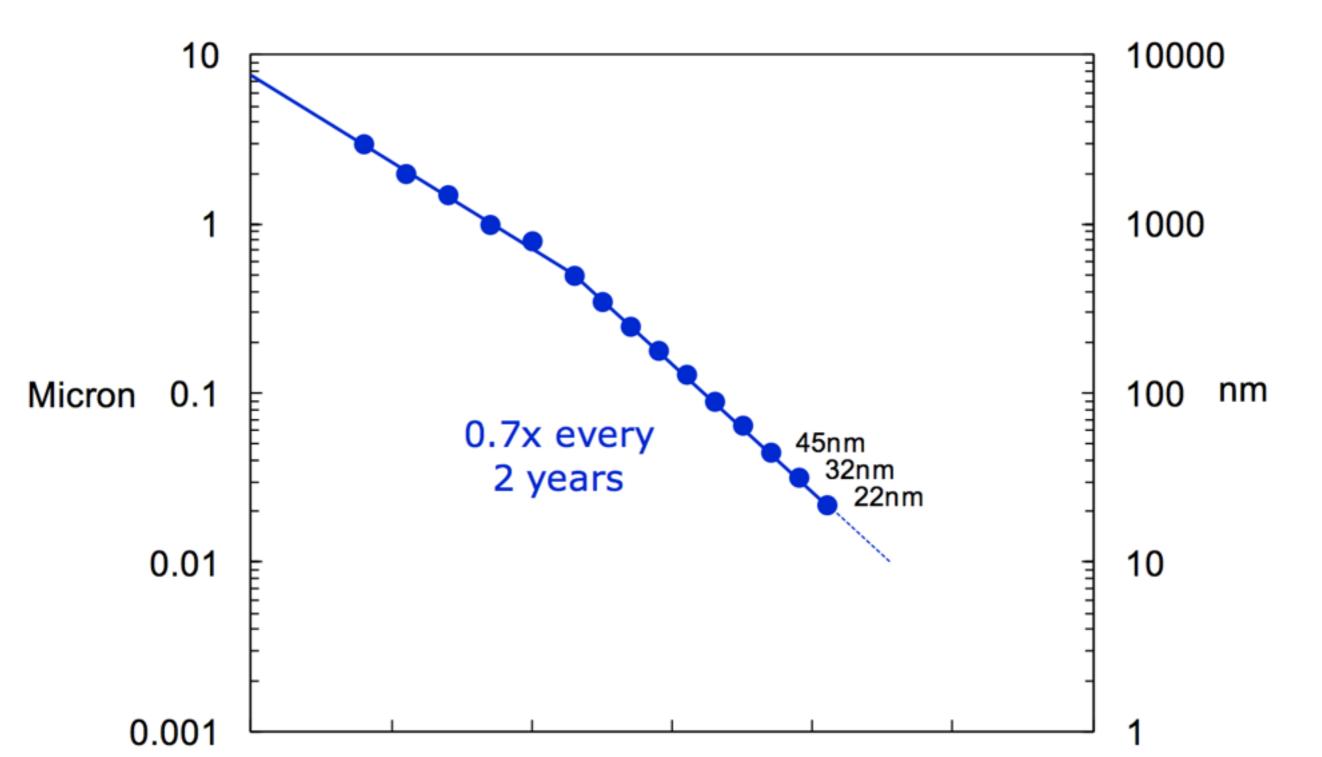
Analog design with deep sub-micron devices

Scott Fairbanks

Moore's law

The density of transistors doubles every 18 months



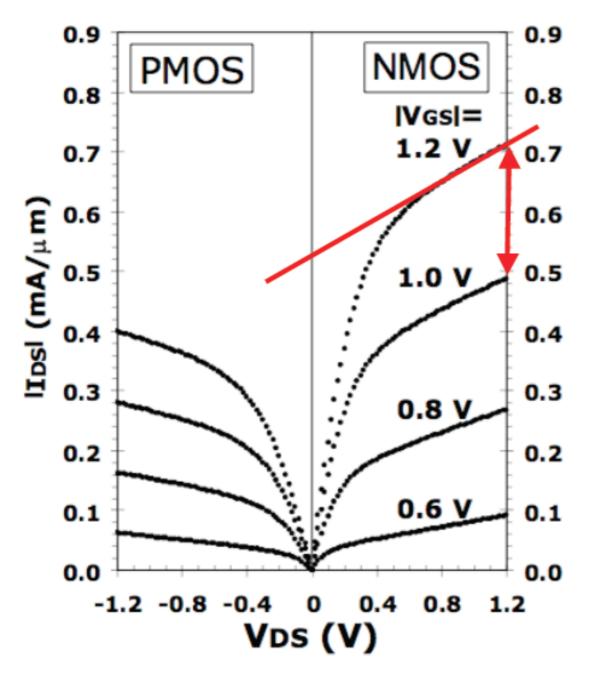
Compromised Gain

Modern digital Classic Characteristic Curves for nMOSFET 50 V GS-VTH=7 V Drain current [arbitary unit] .3 linear region 40 6 V di 30 dv .2 5 V Id (A) 20 saturation region 4 V .1 3 V. 10 2 V 1 V 0 10 2 6 8 0 4 Û .8 .2 .4 1.0 Û .6 Vds (V) Drain to source voltage [V]

 $Gain = g_m * r_o$

 $= g_m * di/dv$

self-gain for 65 nm digital CMOS



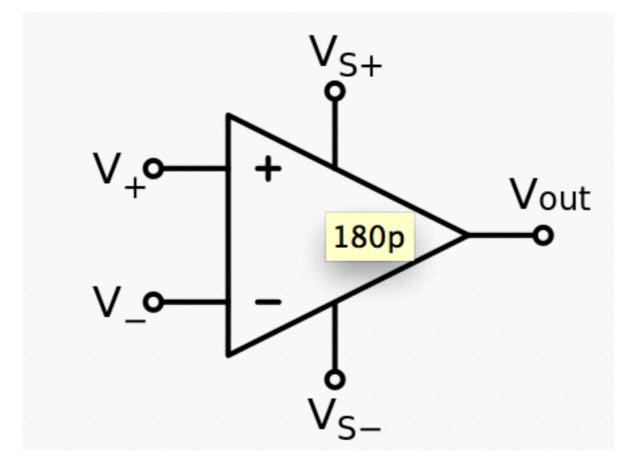
$$g_m \approx \frac{0.2 \text{ mA}/\mu\text{m}}{0.2 \text{ V}} = 1 \text{ mS}/\mu\text{m}$$
$$r_o \approx \frac{1.2 \text{ V}}{0.18 \text{ mA}/\mu\text{m}} \approx 7 \text{ K}\Omega-\mu\text{m}$$

$$A_v(\max) = g_m r_o \approx 7$$

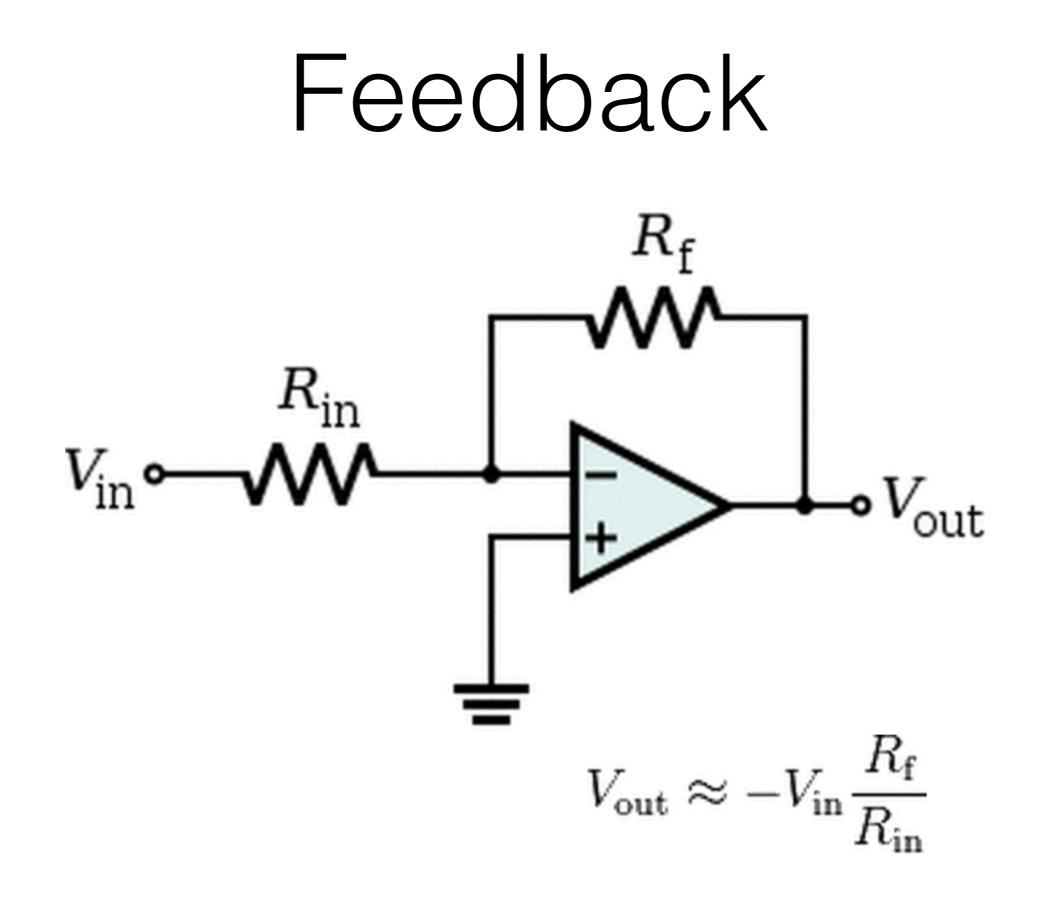
C.-H. Jan. et al., 2005 IEDM

Lundstrom EE-612 F08

Operational Amplifier



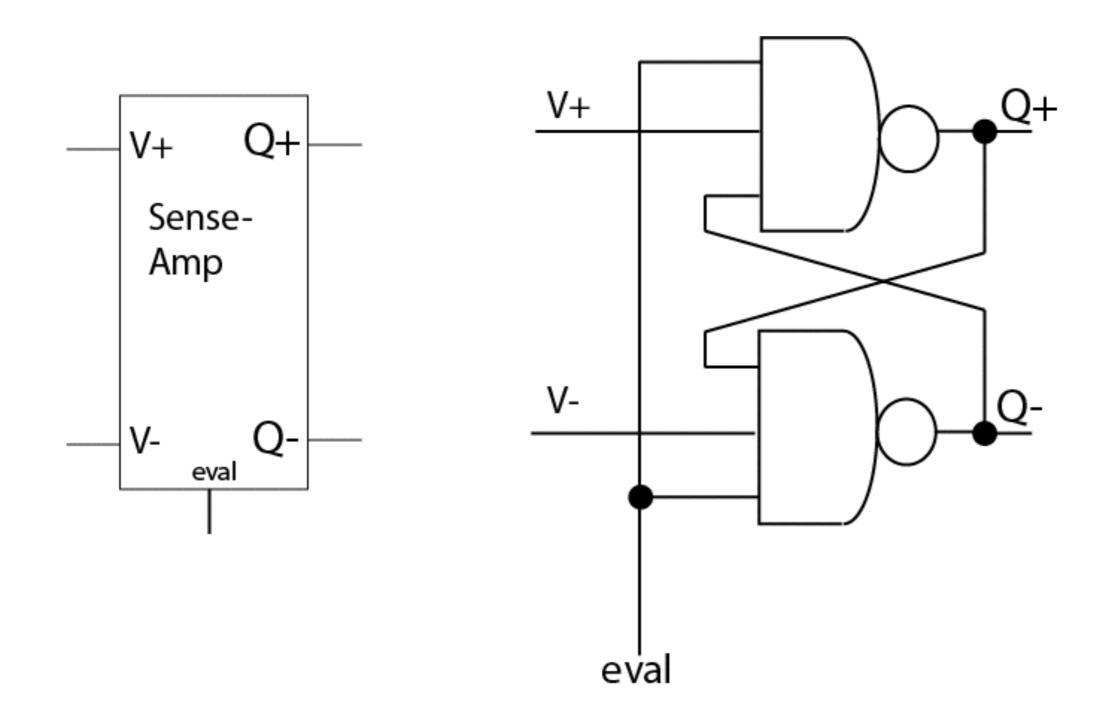
$$V_{\rm out} = A_{\rm OL} (V_+ - V_-)$$

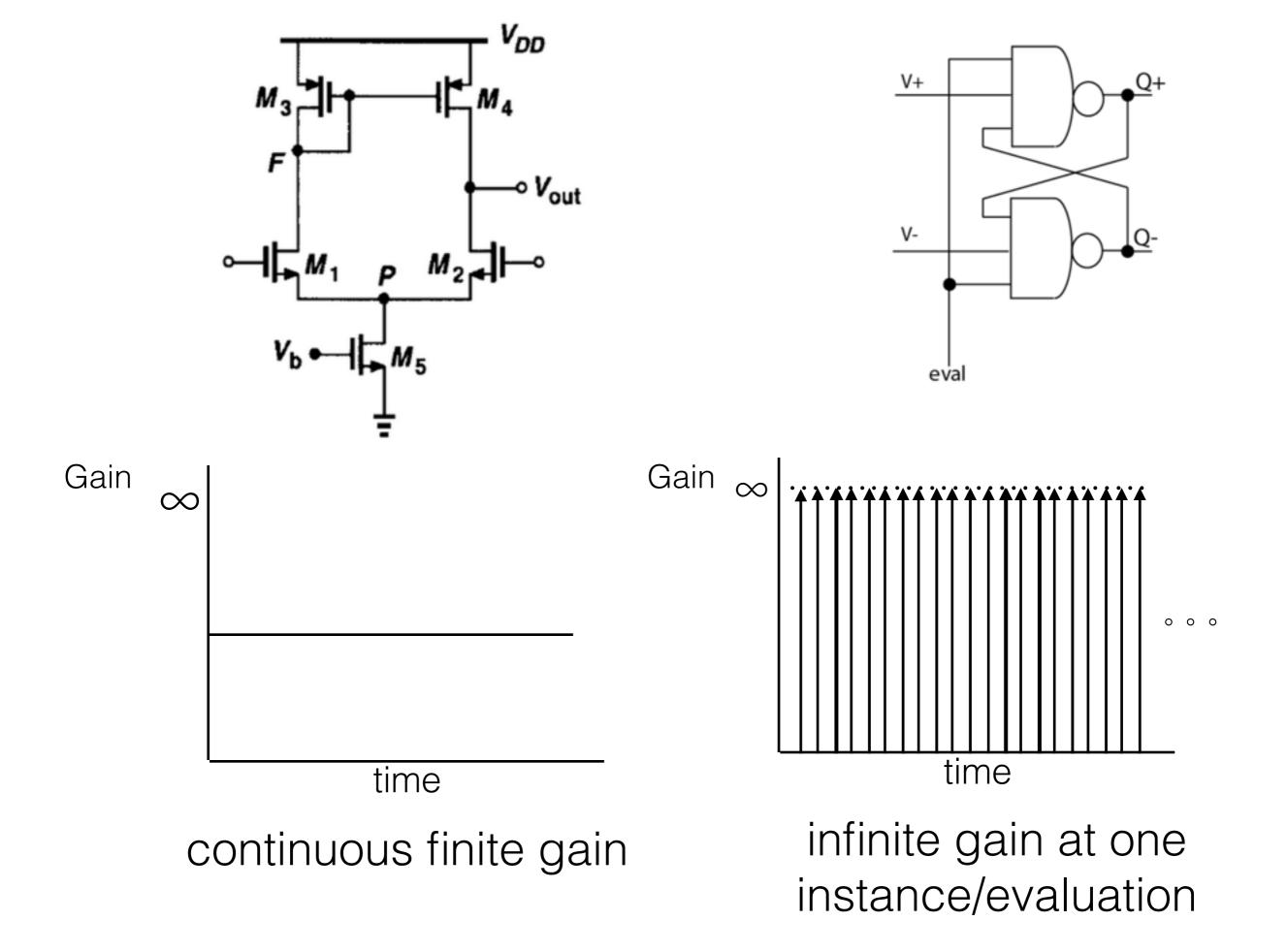


Deep submicron CMOS devices

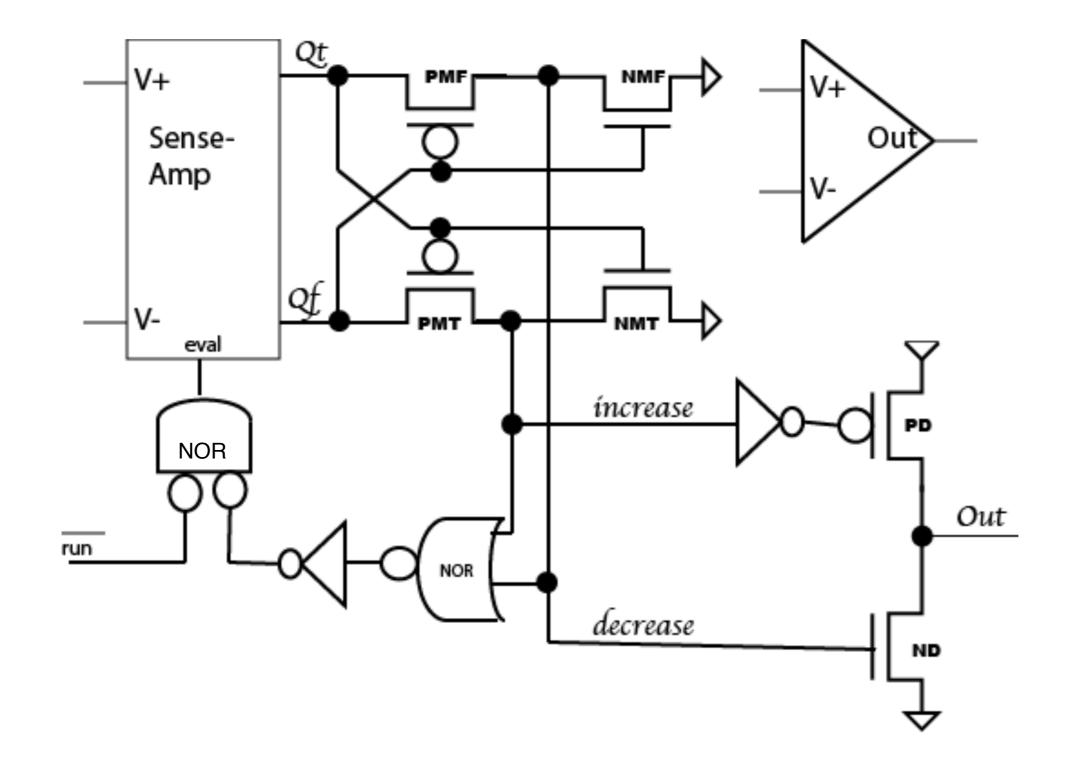


Sense - amplifier

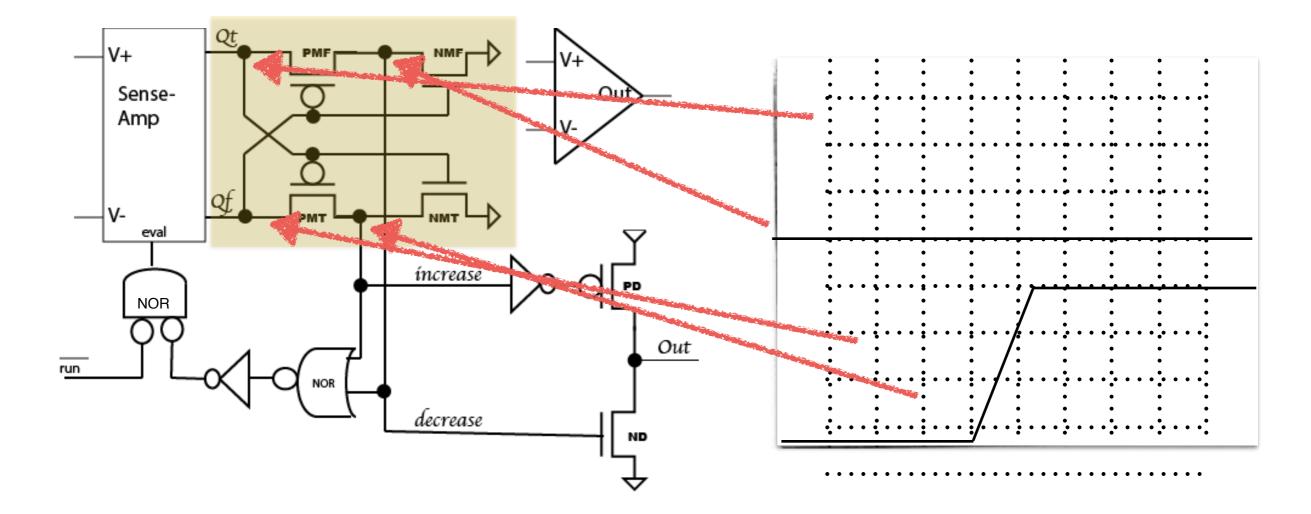




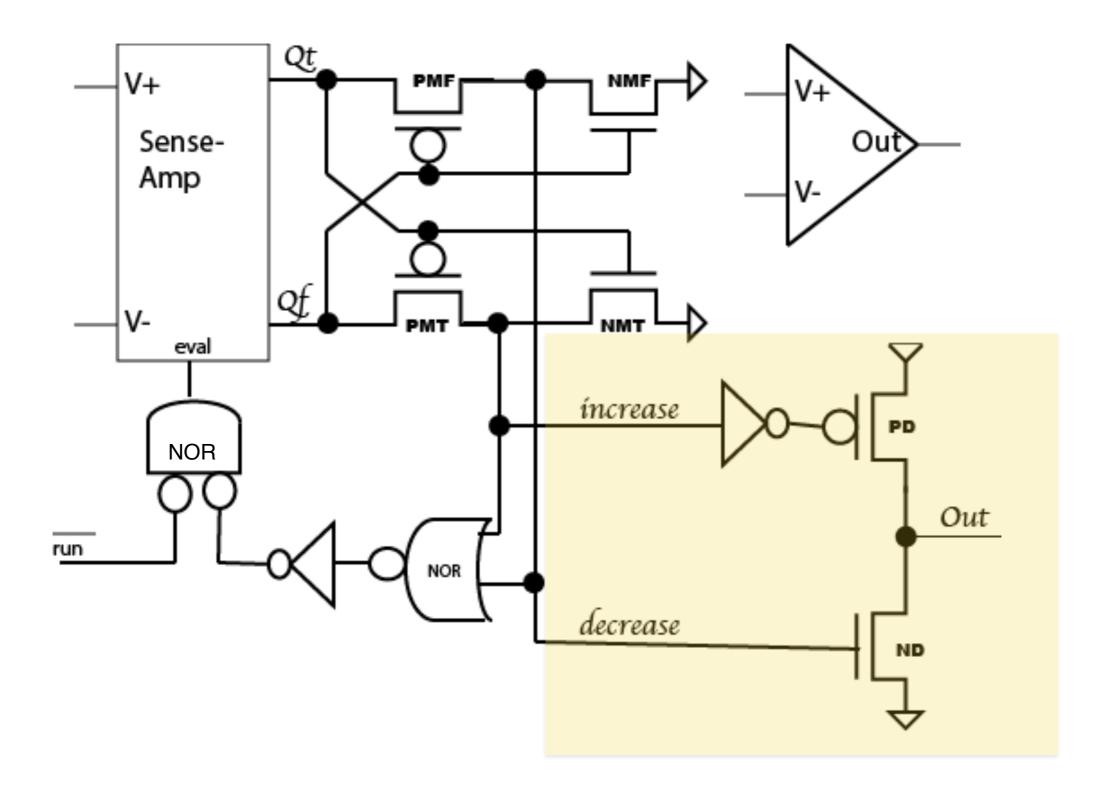
Digital Operational Amplifier



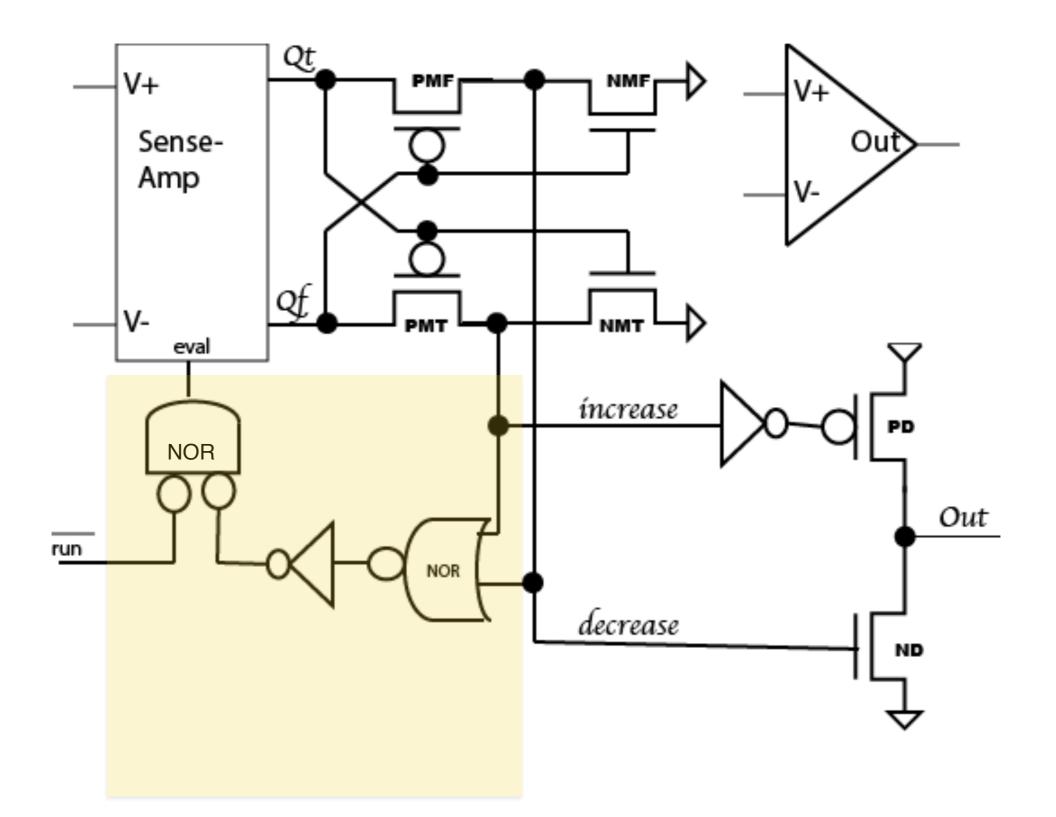
Metastability resolving circuitry



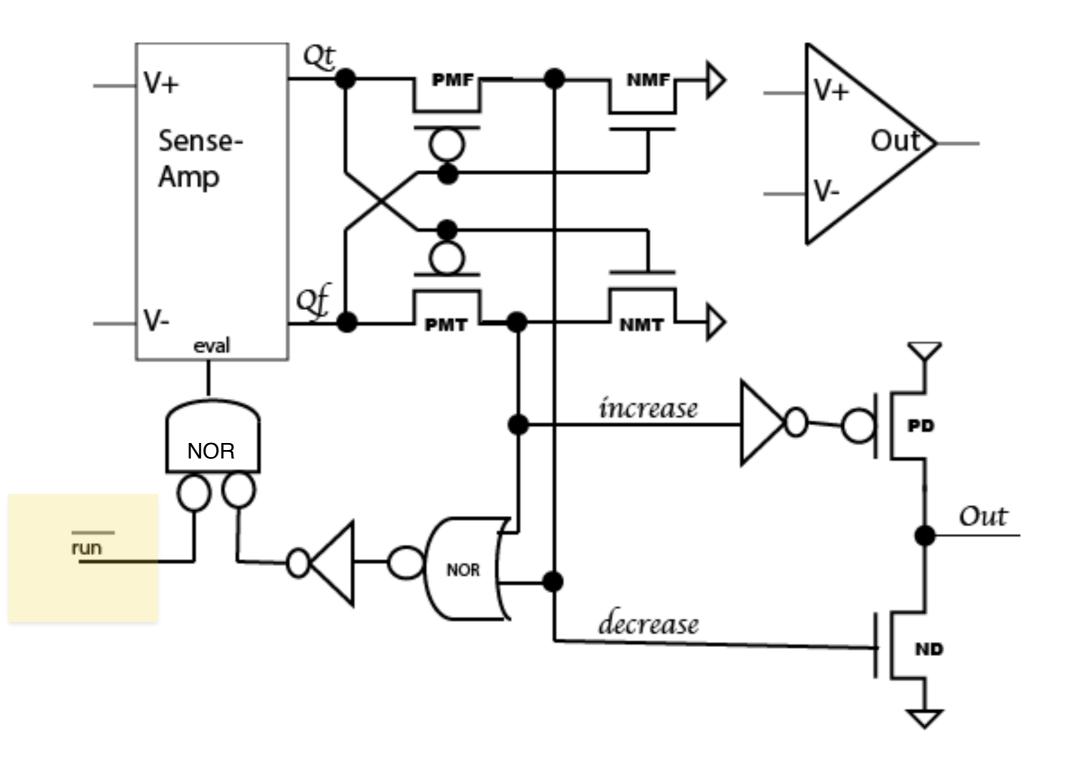
Actuate output voltage

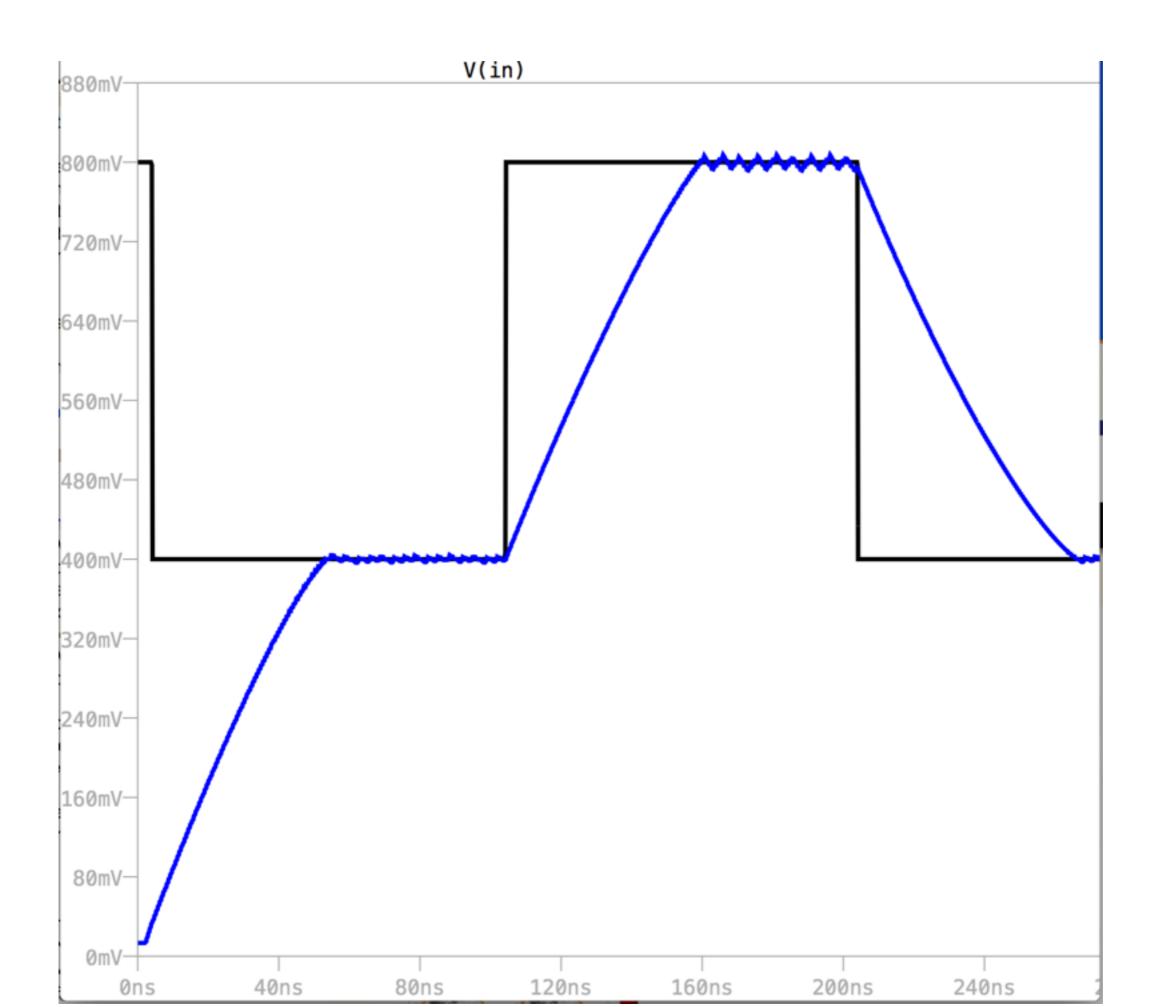


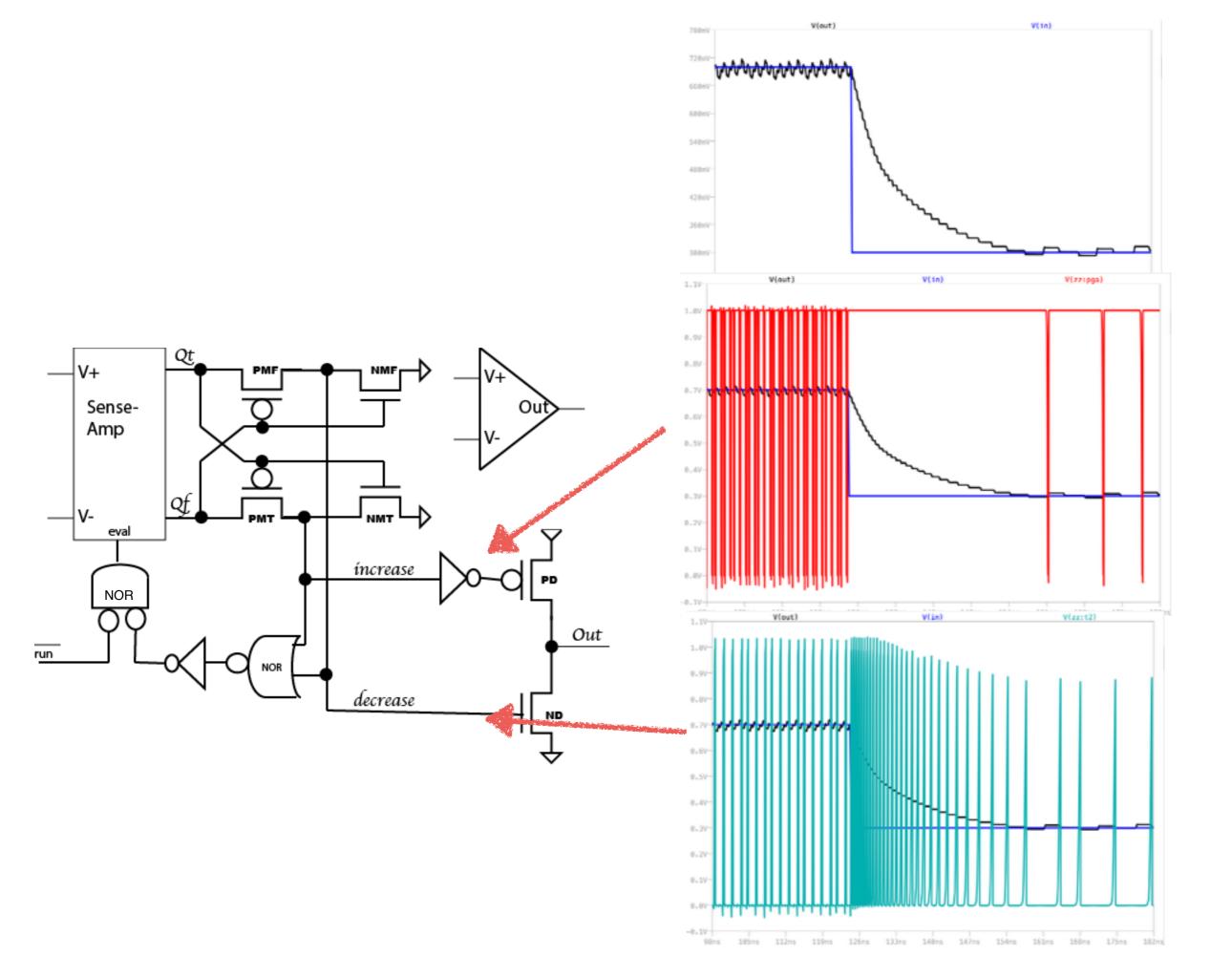
Reset



Start/stop



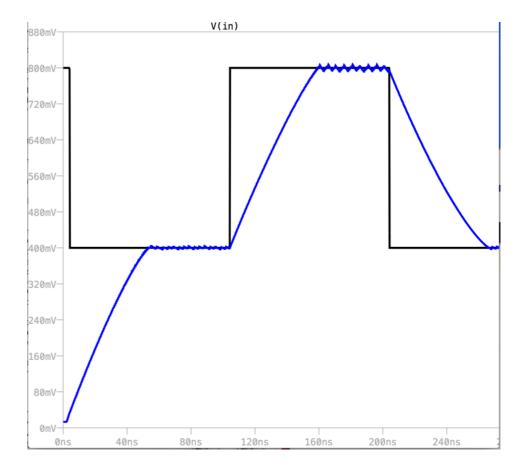




Advantages

- Robust functionality in the face of unexpected transistor properties or poor sizing.
- rail-to-rail signaling
- no DC currents
- potential very low power operation
- performance scales in the same direction as transistor integration trends

Weaknesses



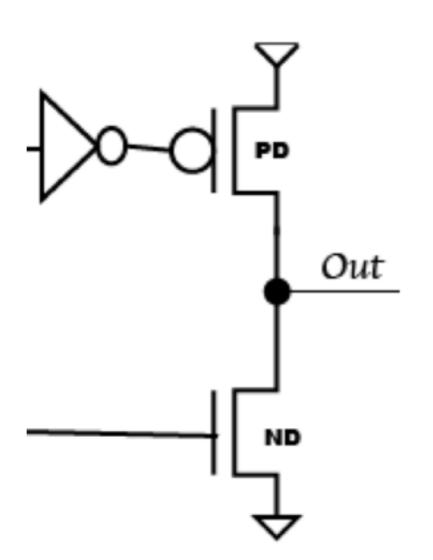
- BW scales as 2-n
- relatively high output resistance
- distortion especially near rails

Bandwidth BW $\propto \frac{1}{(t_{eval})^* (2^{bits+1})}$

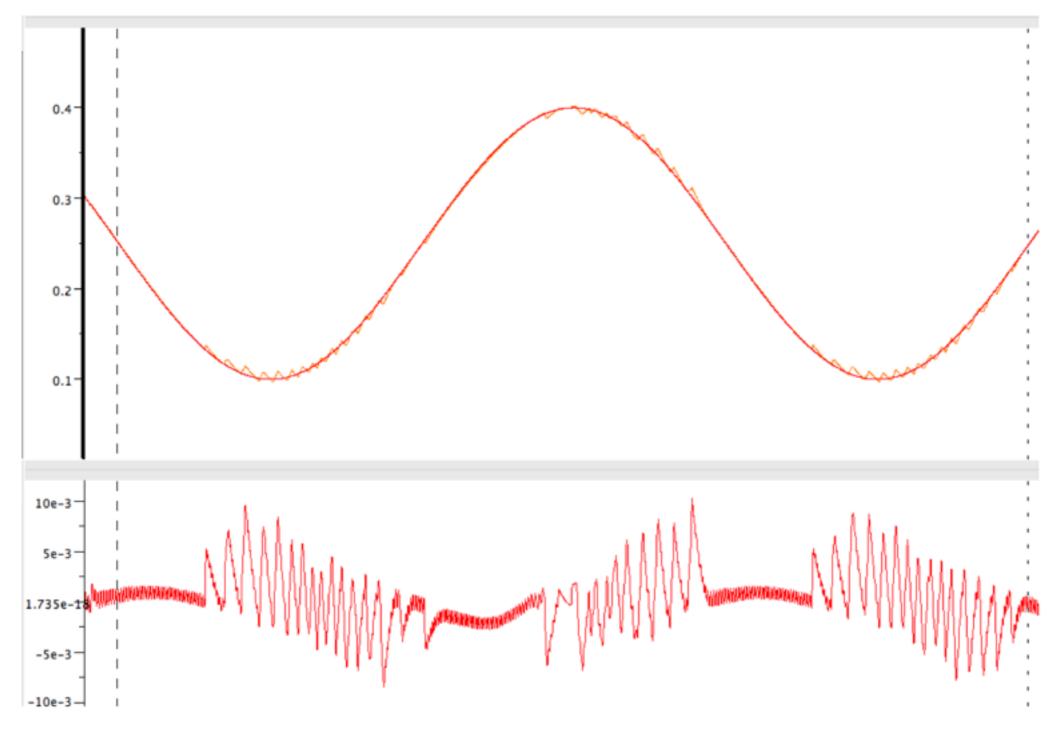
Conventional amplifier:

Gain * BW = Constant

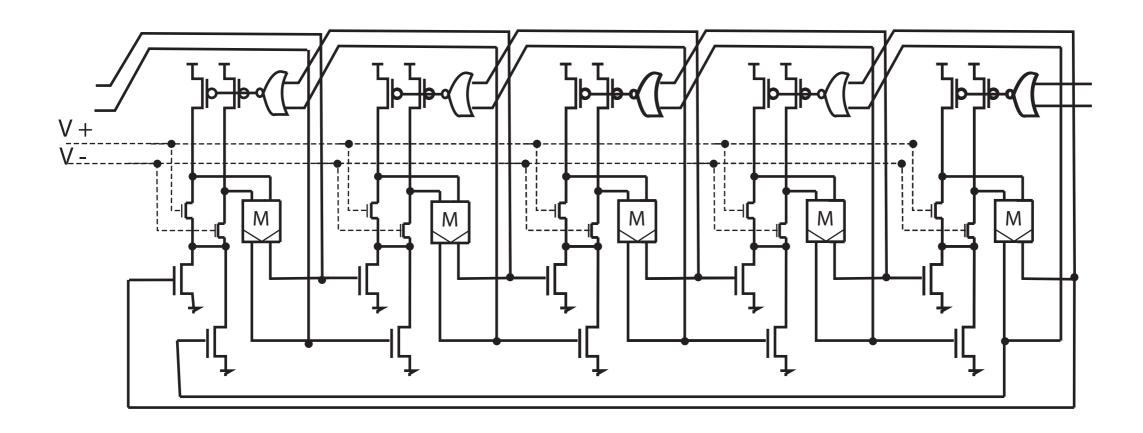
High output resistance

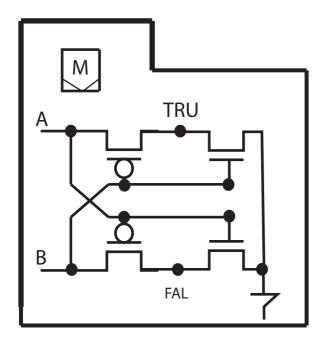


Distortion



Embellishments





New evaluation every 2 gate delays

transistor matching issues

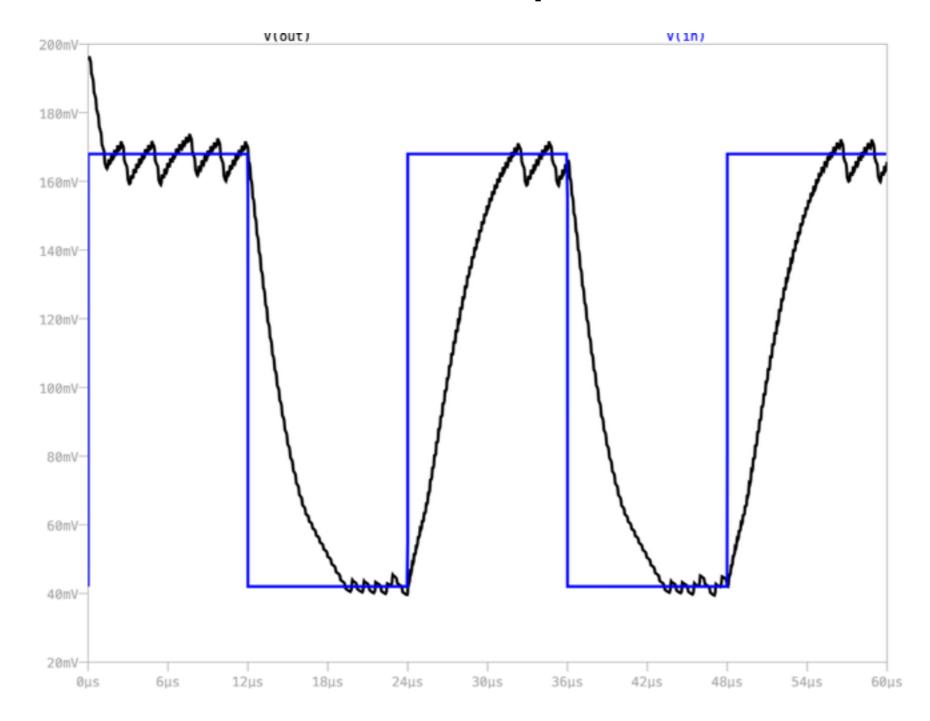
Application: Analog datapath

Area of 64 bit microprocessors largely determined by wire routing.

With a 1V supply, four bits of resolution (62.5mV / level) easily achievable with this amplifier.

Upper limit of 16x area reduction.

Applications: ultra-low power



Switched Capacitor amplifier

